



1200V
10A

- Motor Drivers
 - AC and DC servo drive amplifier
 - UPS (Uninterruptible Power Supplies)
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- Low switching losses
 - Low $V_{ce(sat)}$ with positive temperature coefficient
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Gate-emitter Threshold Voltage	$V_{GE(th)}$	$V_{GE}=V_{CE}, I_C = 0.5mA, T_{vj}=25^{\circ}C$	5.2	6.0	6.8	V		
Collector-Emitter Cut-off Current	I_{CES}	$V_{CE}=1200V, V_{GE}=0V, T_{vj}=25^{\circ}C$			1.0	mA		
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=10A, V_{GE}=15V, T_{vj}=25^{\circ}C$		1.85	2.50	V		
		$I_C=10A, V_{GE}=15V, T_{vj}=150^{\circ}C$		2.25				
Gate Charge	Q_G			0.12		uC		
Input Capacitance	C_{ies}	$V_{CE}=25V, V_{GE}=0V,$ $f=1MHz, T_{vj}=25^{\circ}C$		0.9		nF		
Reverse Transfer Capacitance	C_{res}			0.03		nF		
Gate-Emitter leakage current	I_{GES}	$V_{CE}=0V, V_{GE}=20V, T_{vj}=25^{\circ}C$			400	nA		
Turn-on Delay Time	$t_{d(on)}$	$I_C = 10A$ $V_{CE} = 600V$ $V_{GE} = \pm 15V$ $R_G=47\Omega$ $T_{vj}=25^{\circ}C$		84		ns		
Rise Time	t_r			80		ns		
Turn-off Delay Time	$t_{d(off)}$				150		ns	
Fall Time	t_f				145		ns	
Energy Dissipation During Turn-on Time	E_{on}				1.20		mJ	
Energy Dissipation During Turn-off Time	E_{off}				0.60		mJ	
Turn-on Delay Time	$t_{d(on)}$		$I_C = 10A$ $V_{CE} = 600V$ $V_{GE} = \pm 15V$ $R_G=47\Omega$ $T_{vj}=125^{\circ}C$		85		ns	
Rise Time	t_r				62		ns	
Turn-off Delay Time	$t_{d(off)}$					270		ns
Fall Time	t_f					170		ns
Energy Dissipation During Turn-on Time	E_{on}				1.50		mJ	
Energy Dissipation During Turn-off Time	E_{off}				0.8		mJ	
SC Data	I_{sc}	$T_p \leq 10\mu s, V_{GE}=15V, T_{vj}=150^{\circ}C,$ $V_{cc}=900V, V_{CEM} \leq 1200V$			70		A	



Repetitive Peak Reverse Voltage	V_{RRM}	$T_{vj}=25^{\circ}\text{C}$	1200	V
Continuous DC Forward Current	I_F		10	A
Repetitive Peak Forward Current	I_{FRM}	$t_p=1\text{ms}$	20	A
I^2t -value	I^2t	$V_R=0, t_p=10\text{ms}, T_{vj}=150^{\circ}\text{C}$	16.0	A^2s

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Collector-Emitter Voltage	V_{CES}	$V_{GE}=0V, I_C=1mA, T_{vj}=25^{\circ}C$	1200	V
Continuous Collector Current	I_C	$T_c=100^{\circ}C, T_{vjmax}=175^{\circ}C$	10	A
Repetitive Peak Collector Current	I_{CRM}	$tp=1ms$	20	A
Gate-Emitter Voltage	V_{GES}	$T_{vj}=25^{\circ}C$	± 20	V
Total Power Dissipation	P_{tot}	$T_c=25^{\circ}C, T_{vjmax}=175^{\circ}C$	92	W

Gate-emitter Threshold Voltage	$V_{GE(th)}$	$V_{GE}=V_{CE}, I_C=0.5mA, T_{vj}=25^{\circ}C$	5.2	6.0	6.8	V
Collector-Emitter Cut-off Current	I_{CES}	$V_{CE}=1200V, V_{GE}=0V, T_{vj}=25^{\circ}C$			1.0	mA
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=10A, V_{GE}=15V, T_{vj}=25^{\circ}C$		1.85	2.25	V
		$I_C=10A, V_{GE}=15V, T_{vj}=125^{\circ}C$		2.15		
Gate Charge	Q_G			0.09		μC
Input Capacitance	C_{ies}	$V_{CE}=25V, V_{GE}=0V, f=1MHz, T_{vj}=25^{\circ}C$		1.35		nF
Reverse Transfer Capacitance	C_{res}			0.08		nF
Gate-Emitter leakage current	I_{GES}	$V_{CE}=0V, V_{GE}=20V, T_{vj}=25^{\circ}C$			400	nA
Turn-on Delay Time	$t_{d(on)}$	$I_C=10A$ $V_{CE}=600V$ $V_{GE}=\pm 15V$ $R_G=47\Omega$ $T_{vj}=25^{\circ}C$		80		ns
Rise Time	t_r			78		ns
Turn-off Delay Time	$t_{d(off)}$			150		ns
Fall Time	t_f			148		ns
Energy Dissipation During Turn-on Time	E_{on}			1.10		mJ
Energy Dissipation During Turn-off Time	E_{off}			0.83		mJ



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Turn-on Delay Time	$t_{d(on)}$	$I_C = 10A$ $V_{CE} = 600V$ $V_{GE} = \pm 15V$ $R_G = 47\Omega$ $T_{vj} = 125^\circ C$		82		ns
Rise Time	t_r			63		ns
Turn-off Delay Time	$t_{d(off)}$			258		ns
Fall Time	t_f			180		ns
Energy Dissipation During Turn-on Time	E_{on}			1.47		mJ
Energy Dissipation During Turn-off Time	E_{off}			0.81		mJ
SC Data	I_{sc}	$T_p \leq 10\mu s, V_{GE} = 15V, T_{vj} = 150^\circ C,$ $V_{cc} = 900V, V_{CEM} \leq 1200V$		70		A

Repetitive Peak Reverse Voltage	V_{RRM}	$T_j = 25^\circ C$		1200	V
Continuous DC Forward Current	I_F			10	A
Repetitive Peak Forward Current	I_{FRM}	$t_p = 1ms$		20	A
I^2t -value	I^2t	$V_R = 0, t_p = 10ms, T_j = 125^\circ C$		16.0	A^2s

Forward Voltage	V_F	$I_F = 10A, T_{vj} = 25^\circ C$		2.0	2.80	V
		$I_F = 10A, T_{vj} = 125^\circ C$		2.10		
Recovered Charge	Q_{rr}	$I_F = 10A$		0.90		μC
Peak Reverse Recovery Current	I_{rr}	$V_R = 600V$ $-di_F/dt = 500A/\mu s$		12.5		A
Reverse Recovery Energy	E_{rec}	$T_{vj} = 25^\circ C$		0.25		mJ
Recovered Charge	Q_{rr}	$I_F = 10A$		1.70		μC
Peak Reverse Recovery Current	I_{rr}	$V_R = 600V$ $-di_F/dt = 500A/\mu s$		10.4		A
Reverse Recovery Energy	E_{rec}	$T_{vj} = 125^\circ C$		0.50		mJ

Reverse Voltage	V_{RRM}	$T_j=25^\circ\text{C}$	1600	V
Current	$I_{F(AV)}$	$T_c=100^\circ\text{C}$	10	A
Maximum RMS Current at Rectifier Output	I_{RMSM}	$T_c=100^\circ\text{C}$	20	A



Isolation voltage	V_{isol}	$t=1\text{min}, f=50\text{Hz}$	2500			V
Maximum Junction Temperature	T_{jmax}				175	°C
Operating Junction Temperature	$T_{vj op}$		-40		150	°C
Storage Temperature	T_{stg}		-40		150	°C
Stray-inductance-module	L_{SCE}			60		nH
Module lead resistance, terminals-chip	$R_{cc'+EE'}$	$T_C=25^\circ\text{C}$, per switch		4.0		mΩ
	$R_{AA'+CC'}$			3.0		
Thermal Resistance Junction-to Case	$R_{\theta JC}$	per IGBT-inverter			1.25	K/W
		per Diode-inverter			1.64	
		per IGBT-brake-copper			1.30	
		per Diode-chopper			2.39	
		per Diode-rectifier			1.17	
Thermal Resistance Case-to Sink	$R_{\theta CS}$	per IGBT-inverter		0.40		K/W
		per Diode-inverter		0.72		
		per IGBT-brake-copper		0.53		
		per Diode-chopper		0.77		
		per Diode-rectifier		1.10		
		per Module		0.02		
Mounting Force Per Clamp	F		3.0		6.0	N
Weight of Module	G			180		g









